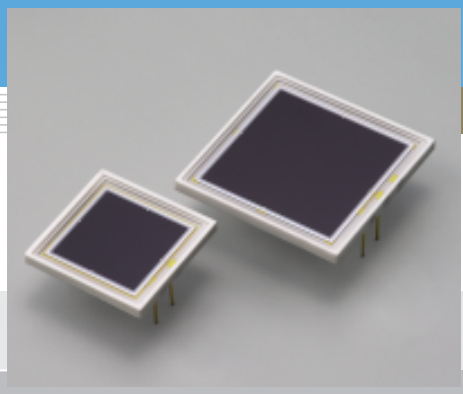


Si PIN photodiode S3204/S3584 series

Large area sensors for scintillation detection



S3204/S3584 series are large area Si PIN photodiodes having an epoxy resin window. These photodiodes are also available without window.

Features

- Higher sensitivity and low dark current than conventional type
- Sensitivity matching with BGO and CsI (TI) scintillators
- High quantum efficiency QE=85 % ($\lambda=540$ nm)
- Low capacitance
- High-speed response
- High stability
- Good energy resolution

Applications

- Scintillation detectors
- Calorimeters
- Hodoscopes
- TOF counters
- Air shower counters
- Particle detectors, etc.

General ratings / Absolute maximum ratings

Type No.	Dimensional outline	Window material	Active area (mm)	Absolute maximum rating			
				Reverse voltage VR Max. (V)	Power dissipation P (mW)	Operating temperature Topr (°C)	Storage temperature Tstg (°C)
S3204-05	①	Epoxy resin	18 × 18	150	100	-20 to +60	-20 to +80
S3204-08				100			
S3584-05	②		28 × 28	150			
S3584-08				100			

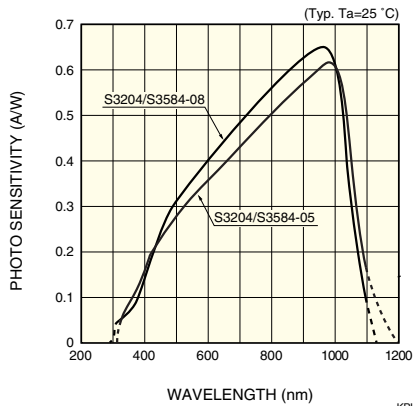
Electrical and optical characteristics (Typ. $T_a=25$ °C, unless otherwise noted)

Type No.	Spectral response range λ (nm)	Peak sensitivity wavelength λ_p (nm)	Photo sensitivity S				Short circuit current I_{sc} 100 lx		Dark current I_D $V_R=100$ V		Temp. coefficient of I_D T_{CID} (times/°C)	Cut-off frequency f_c $V_R=100$ V -3 dB (MHz)	Terminal capacitance C_t $f=1$ MHz $V_R=100$ V (pF)	NEP $V_R=100$ V ($W/Hz^{1/2}$)
			$\lambda=\lambda_p$ (A/W)	LSO 420 nm (A/W)	BGO 480 nm (A/W)	CsI (TI) 540 nm (A/W)	μA		Typ.	Max.				
S3204-05	320 to 1120	980	0.6	0.19	0.25	0.3	310	15	15	50	1.12	20	80	1.2×10^{-13}
S3204-08	320 to 1100	960	0.66	0.20	0.3	0.36	340	6 *	20 *			20 *	130 *	$6.6 \times 10^{-14} *$
S3584-05	320 to 1120	980	0.6	0.19	0.25	0.3	740	20	100			10	200	1.3×10^{-13}
S3584-08	320 to 1100	960	0.66	0.20	0.3	0.36	780	10 *	30 *			10 *	300 *	$8.6 \times 10^{-14} *$

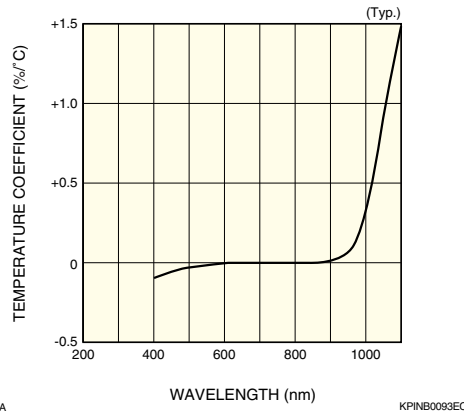
* $V_R=70$ V

Si PIN photodiode S3204/S3584 series

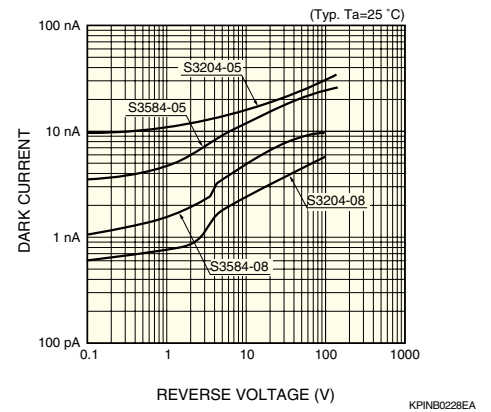
■ Spectral response



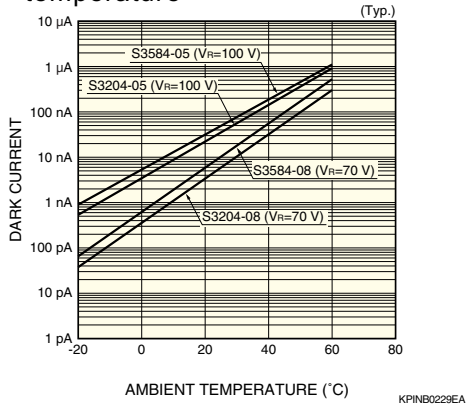
■ Photo sensitivity temperature characteristic



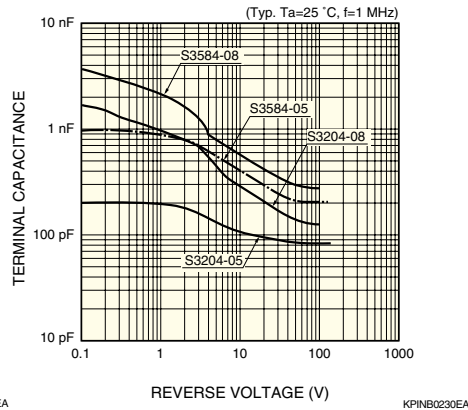
■ Dark current vs. reverse voltage



■ Dark current vs. ambient temperature

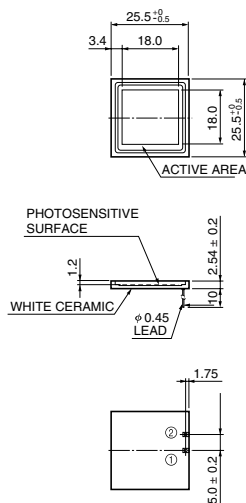


■ Terminal capacitance vs. reverse voltage

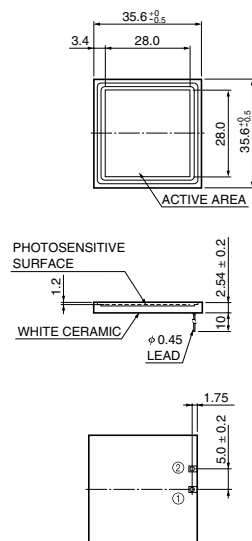


■ Dimensional outlines (unit: mm)

① S3204 series



② S3584 series



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